Form PTO-1449			ATTY DOCKET NO. 24500-000015/US	APPLICATION OF NEW APPLICATION				
INFORMATION DISCLOSURE CITATION IN AN APPLICATION			APPLICANT(S) Valerie BOUSQUET et al.		CONF. NO. Not Yet Assigned			
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	U	.S. PATENT DO	DCUMENTS					
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS		G DATE OPRIATE	
:AKS	US 5,602,418	02/11/1997	Hideaki IMAI et al.					
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AKS	Shuji NAKAMURA et al., "Candela-class high-brightness InGaN/AlGaN double-heterostructure blue-light-emitting diodes", Applied Physics Letters, American Institute of Physics, New York, US, Vol. 64, No. 13, March 28, 1994, pages 1687-1689							
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